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## **Dynamics of mutually coupled semiconductor lasers**

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### **Abstract:**

We present the results of a numerical study of the dynamical behavior of two mutually coupled semiconductor lasers.To do so a four- equations model is adopted together with injection current pulse shaping of each laser alone together with sinusoidal modulation of the injection current of each laser.

The obtained results revealed varieties of dynamics in all the studied cases, which suggest the possibility of safe communication through beating of both lasers signals.

### **Keywords:**

Semiconductor lasers, Mutual coupling, Injection pulse shaping, Injection current modulation, Chaotic dynamics.

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**حركيـــات ليـزري شبــه موصــل متبادلـي األقتـران**  $\bm{p}^{(1)}$ عبيد عليوي $\bm{p}^{(1)},$ حسن عبدالله سلطان $^{(2)},$  دعاء حسين هاشم $^{(2)}$ , علي مهدي جخيم $^{(3)}$ , **)2( جاسب عبذالحسيه مشاري** (1) قسم الفيزياء/ كلية العلوم/ جامعة ذي قار (2) قسم الفيز ياء/ كلية التر بية للعلوم الصر فة/ جامعة البصر ة (1) مديرية التربية/ محافظة ذي قار. العراق

**الخالصــة:**

نقدم في هذا البحث دراسة عددية للتصرف الحركي لليزري شبه موصل متبادلي الأقتران باستعمال انموذج رباعي المستويات والتحكم بشكل نبضة تيار الحقن لكل ليزر على حدة وعن طريق تضمين تيار حقن حييي الشكل لكل ليزر .

أضفت النتائج المحصلة الى حركيات متنوعة في كافة الحالات المدروسة وإمكانية استخدامها جميعا في الأتصالات الآمنة خصوصا بعد مضاربة خرج الليزرين معا وفي جميع الحالات.

ا**لكلمات المفتاحية:** ليزر أشباه الموصلات، الأقتران المتبادل، السيطرة على نبضة الحقن، حركيات فوضوية.

### **Introduction:**

Dynamical behavior of delay- coupled semiconductor lasers (SCLs) studies are of continuing interest for fundamental and technical curiosities. For the former SCLs are an excellent model systems for studying the properties of delay- coupled oscillators that occur in many systems, like complex networks [1], excitable layers [2], neural networks [3], etc.

The delay time arises naturally as a result of the finite propagation time of light from one laser to the other. The influence of time delay in the coupling becomes important when the delay introduced for example by the spatial distance of the individual oscillators is of the same order or larger than the characteristic frequencies of the oscillators [4].

In coupled SCLs system, an amplitude fluctuation in one laser leads to a carrier density fluctuation through amplitude- phase coupling or linewidth enhancement factor,  $\alpha$ , in the same laser. The  $\alpha$  - factor influences several fundamental aspects of all SCLs, such as linewidth, the chirp under current modulation and the mode stability [5].

In the present article we present results of numerical simulation studies of the effect of pulse shaping of the injection of SCLs dynamics on each laser alone together with the modulation of injection current on the dynamics of each and both lasers at the same time.

#### **Mathematical Model:**

The mutually coupled semiconductor lasers were studied numerically by number of authors using varieties of theoretical models [6-12]. The following set of equations describe the time evolution of the complex, slowly varying electric field of laser (1) and laser (2),  $E_1$  and  $E_2$  respectively, and the carriers number in both lasers,  $N_1$  and  $N_2$ respectively [13]. Both lasers beams enter each laser via the rare mirror of each laser while the laser output leave each laser via the output coupler of each laser, is shown in fig.  $(1)$ :



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Fig. (1): Two coupled semiconductor lasers.

$$
\dot{E}_1(t) = \frac{1}{2}(1 + i\alpha)[G_{1-}\gamma]E_1 + kE_2(t - \tau) \qquad \qquad \dots (1)
$$

$$
\dot{E}_2(t) = \frac{1}{2}(1 + i\alpha)[G_2 - \gamma]E_2 + kE_1(t - \tau) \tag{2}
$$

$$
\dot{N}_1(t) = \frac{I}{q} - \gamma_e N_1 - G_1 |E_1|^2 \qquad \qquad \dots (3)
$$

$$
\dot{N}_2(t) = \frac{I}{q} - \gamma_e N_2 - G_2 |E_2|^2 \qquad \qquad \dots (4)
$$

 $\alpha$ , is the linewidth enhancement factor,  $\gamma$  is the cavity losses, k is the coupling rate between the two lasers,  $\tau$  is the coupling or delay time, I is the injection current of each laser  $(I_1 = I_2 = I)$ , q is the electronic charge,  $\gamma_e$  is the carrier decay rate,  $G_1$  and  $G_2$ are taken as follows:

$$
G_1 = \frac{g(N_1 - N_t)}{1 + \epsilon |E_1|^2} \tag{5}
$$

$$
G_2 = \frac{g(N_2 - N_t)}{1 + \epsilon |E_2|^2} \tag{6}
$$

where g is the differential gain,  $N_t$  is the carrier value at transparency and  $\epsilon$  is the gain saturation parameter. The coupling delay terms  $kE_2(t - \tau)$  and  $kE_1(t - \tau)$  are added to equations (1) and (2) respectively.

The dot over  $E_1$ ,  $E_2$ ,  $N_1$ ,  $N_2$  represent differentiation with time.

In the case of injection current modulation, we have used the sinusoidal form of modulation as follows:

For laser 1: 
$$
I_1 = I_{1dc} + m_1 \sin(2\pi ft)
$$
 ... (7)

For laser 2: 
$$
I_2 = I_{2dc} + m_2 \sin(2\pi ft)
$$
 ... (8)

where  $I_{1,2dc}$  are the constant parts of the injection current in laser (1) and (2) respectively,  $m_1$  and  $m_2$  are the ac parts or modulation depth of both lasers injection currents respectively and *f* is the modulation frequency.

#### **Simulation results:**

To obtain results we have used the fourth order Runge- Kutta method together with Matlab system making use of parameter values given in table (1) for lasers parameters and table (2) for the injection current (I) and solved the set of equations (1-4).Pulse shape is taken as:

$$
I = I_o e^{(\frac{t-a}{b})^c} \qquad \qquad \dots (9)
$$

where  $I_0$  is the injection current, a,b and c are positive numbers.

Description	Parameter	Value	Units
linewidth enhancement factor	$\alpha$	3.5	
cavity loss	ν	288	$ns$ <sup>-</sup>
differential gain	g	$3.2 \times 10^{-6}$	$ns^{-1}$
coupling rate	$\mathbf k$	23	$ns^{-1}$
carrier decay rate	$\gamma_e$	1.66	$ns$ <sup>-</sup>
carrier value at transparency	$N_t$	$1.5 \times 10^{8}$	
gain saturation parameter	$\epsilon$	$5 \times 10^{-7}$	
electronic charge	q	$1.6 \times 10^{-19}$	Coul
delay time	τ	4.75	ns

Table (1): Parameters values used in the simulation.

Table (2): Modulation of injection current parameters.



The resultes are devided into two parts, in the first the effect of pulse shape on the dynamics of intensity produced from the two lasers are studied and in the second the effects of injection current modulation on the intensity from both lasers are studied too.

Part one: input pulse shapes are presented in fig.(2) where it can be seen the varieties of injection pulses that can be produced electronically depending on the parameters (a) and (b) which represents time in unit of nanosecond and the third parameter c wich is dimensionless.

These pulses were used to represents the injection current of both lasers, to laser 1 first only then to laser 2 only, the results of both are shown in fig.(3) and fig.(4)

respectively. The application of these pulses have led to varieties of laser signals in comparison to the case of dc injection current to both lasers (not shown). This happen to laser 1 only then to laser 2.

When this method is applied to both lasers at the same time should lead to new complexsignals, which can be used in various applications especially in communications.

Part two: the dynamics of the two lasers are investigated under the injection current modulation given in equations (7) and (8). Each injection current which vary with time since the ac part of it is written in a sinusoidal form. Figs.(5-7) shows varieties of dynemics by modulating the injection current of laser 1 only while figs. (8-11) are for the modulating of laser 2 current only. Even for low dc current and ac one both lasers intensity shows chaos in the frequency range  $10^{12} - 10^{14}$  Hz (fig 5(c,d,e)). Another forms of laser intensity appears for high  $I_{ac}$  values and frequncy range ( 10<sup>7</sup> −  $10^{14}$  Hz) and even for higher  $I_{dc}$  and  $I_{ac}$ . All this occurs for both lasers signals. Selfpulsing occurs too (fig  $5(a)$ , fig $6(a)$ , fig $7(c$  and d) and so on in all figures). In the two modulation cases i.e for laser 1 or laser 2 alone each times both lasers signal affected alot by the modulation of the injection current in comparison with no modulation case.

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(1):  $(2.49 \times 10^{-9}, 2.5 \times 10^{-9}, 0.5)$ ,  $(2)$ :  $(2.49 \times 10^{-9}, 2.5 \times 10^{-9}, 0.7)$ ,  $(3)$ :  $(2.49 \times$  $10^{-9}$ ,  $2.5 \times 10^{-9}$ , 1), (4):  $(2.49 \times 10^{-9}, 2.5 \times 10^{-9}, 2)$ ,  $(5)$ :  $(2.49 \times 10^{-9}, 2.5 \times 10^{-9})$  $10^{-9}$ , 3), (6):  $(2.49 \times 10^{-9}, 2.5 \times 10^{-9}, 4)$ ,  $(7)$ :  $(2.49 \times 10^{-9}, 2.5 \times 10^{-9}, 30)$ , (8):  $(2.49 \times 10^{-7}, 2.5 \times 10^{-7}, 90), (9)$ :  $(2.49 \times 10^{-1}, 2.5 \times 10^{-1}, 90)$ .



Fig(3): In each figure(1-9), left coloum is the, laser(1) signal, right coloum, laser (2) signal for parameters values given table (1) with injection signal shown in fig.(2) in same sequence as the input current signal. In injection current given in eq(3) only.

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Fig(4): Same as in fig.(3) but injection current of laser 2 given in  $gg(4)$  only.

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Fig(5): In each figure, top is the laser 1 signal, boffon is laser 2 signal as a result of frequency modulating the current in equation(3) for constant dc injection current=0.065 and injection depth m=0.01 and (a)  $f(H_z)$ =10<sup>7</sup>, (b)  $f(H_z)=10^9$ , (c)  $f(H_z)=10^{12}$ , (d)  $f(H_z)=10^{13}$ , (e)  $f(H_z)=10^{14}$ .<br>223



Fig(6) : The same as in fig.(5) but for dc current  $I=0.15$  and m=0.1 and (a) f(H\_, )=10" , (b) f(H\_, )=10" , (c)  $\operatorname{f}(H_x) {=} 10^{\circ}$  , (d)  $\operatorname{f}(H_x) {=} 10^{10}$  , (e)  $\operatorname{f}(H_x) {=} 10^{12}$  , (f)  $\operatorname{f}(H_x) {=} 10^{14}.$ 



Fig(7): Same as in fig.(5) but do current  $I = 0.65$  and m=0.1 and (a)  $f(H_x)=10^8$ , (b)  $f(H_x)=10^9$ , (c)  $f(H_x)=10^{10}$ , (d)  $f(H_x)=10^{14}$ .



Fig(8) : Same as in fig.(5) but modulating the injection current for laser 2 in equation(4) only and  $I = 0.065$ , m=0.01 and (a) f(H\_,<br>)=10' , (b) f(H\_,<br>)=10' , (c) f(H\_,<br>)=10'^2 , (d) f(H\_,<br>)=10'^2 , (e) f(H\_,<br>)=10'^4 .



Fig(9): Same as in fig.(8) for  $I_{dc} = 0.15$ , m=0. 1 and (a)  $f(H_x) = 10^7$ , (b)  $f(H_x) = 10^8$ , (c)  $f(H_x) = 10^9$ , (d)  $f(H_x)=10^{10}$ , (e)  $f(H_x)=10^{12}$ , (f)  $f(H_x)=10^{14}$ .



 $f(H_x)=10^{14}$ .



Fig(11): Same as in fig.(10)but for  $I_{dc} = 0.15$ , m=0.01 and (a)  $f(H_x)=10^{11}$ , (b)  $f(H_x)=10^{12}$  and for  $I_{dc} = 0.15$ and m=0. 1 (c)  $f(H_r)$ =10<sup>11</sup>, (d)  $f(H_r)$ =10<sup>12</sup> and for  $I_{dc}$  = 0.65, m=0. 01 and (e)  $f(H_r)$ =10<sup>11</sup>, (f)  $f(H_r)$ =10<sup>12</sup>.

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#### **Conclusions**:

Introducing of various types of injection current signal to two mutually coupled semiconductor lasers leds to new dynamics of the high intensity extracted from both lasers. Modulating the injection current of each laser alone leds to dynamics in the shape of self-pulsing or breathing and chaos.

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